

Marking Information

DMN2300UFB-7	Image: Normal systemFrom date code 1527 (YYWW), this changes to:Top ViewTop ViewDot Denotes Drain SideBar Denotes Gate and Source SideImage: Vertical systemImage: V
DMN2300UFB-7B	Top View Bar Denotes Gate and Source Side NI = Part Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current V _{GS} = 4.5V	Steady State	$T_A = +25^{\circ}C \text{ (Note 5)}$ $T_A = +85^{\circ}C \text{ (Note 5)}$ $T_A = +25^{\circ}C \text{ (Note 6)}$	I _D	1.32 0.94 1.78	A
Pulsed Drain Current (Note 7)			IDM	8	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.468	W
Power Dissipation (Note 6)	PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	267	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	104	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	—	—	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	—	—	1	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	—	—	10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	0.45	—	0.95	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
			—	175	mΩ	$V_{GS} = 4.5V, I_D = 300mA$	
Static Drain-Source On-Resistance	R _{DS(ON)}	—	—	240		$V_{GS} = 2.5V, I_D = 250mA$	
			—	360		$V_{GS} = 1.8V, I_D = 100mA$	
Forward Transfer Admittance	Y _{fs}	40	—	_	mS	$V_{DS} = 3V, I_D = 30mA$	
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 300 \text{mA}$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}	_	67.6	_	pF		
Output Capacitance	Coss	_	9.74	_	pF	$-V_{DS} = 20V, V_{GS} = 0V,$ -f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	7.58	_	pF		
Gate Resistance	Rg	_	68.51		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	0.89	_	nC	V _{GS} = 4.5V, V _{DS} = 10V,	
Gate-Source Charge	Q _{gs}	_	0.14		nC		
Gate-Drain Charge	Q _{gd}	_	0.16	_	nC	$I_D = 1A$	
Turn-On Delay Time	t _{D(ON)}		4.92		ns	$V_{DS} = 10V, I_D = 1A$ $V_{GS} = 4.5V, R_G = 6\Omega$	
Turn-On Rise Time	t _R	—	6.93		ns		
Turn-Off Delay Time	t _{D(OFF)}		21.71		ns		
Turn-Off Fall Time	t _F		10.62		ns		

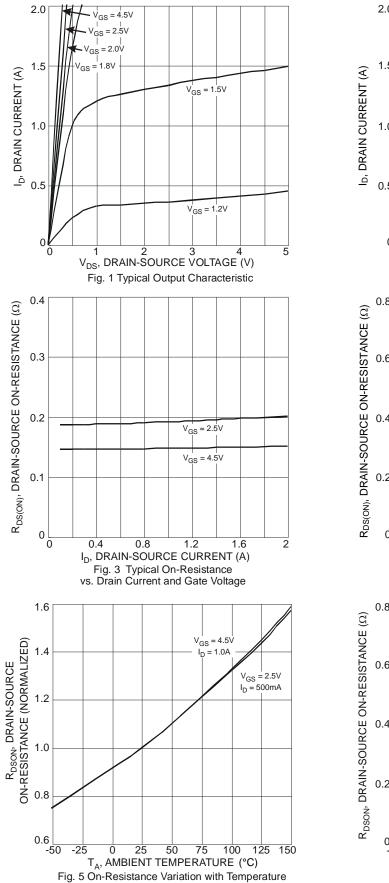
Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 25mm X 25mm square copper plate.
Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

8. Short duration pulse test used to minimize self-heating effect.



DMN2300UFB



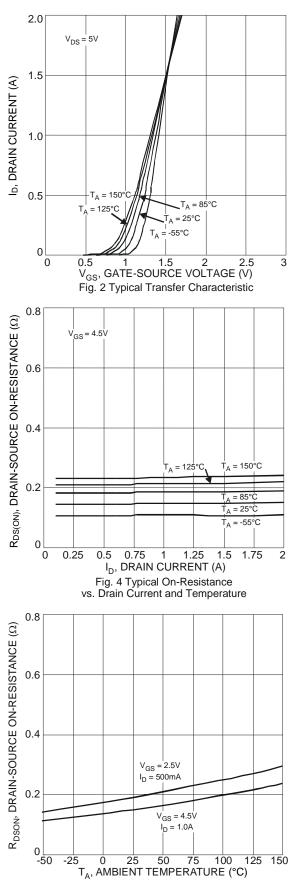
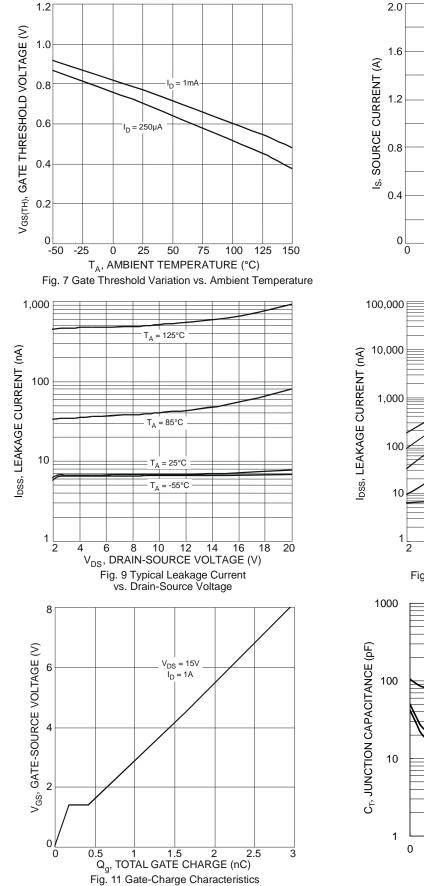
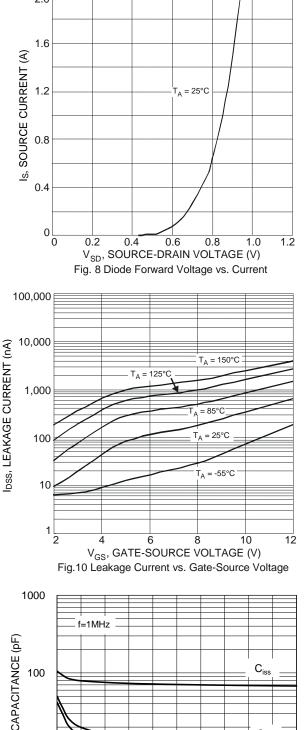


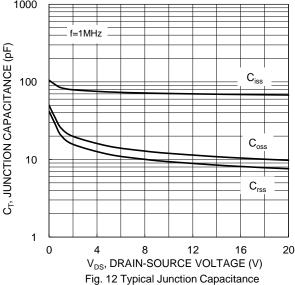
Fig. 6 On-Resistance Variation with Temperature

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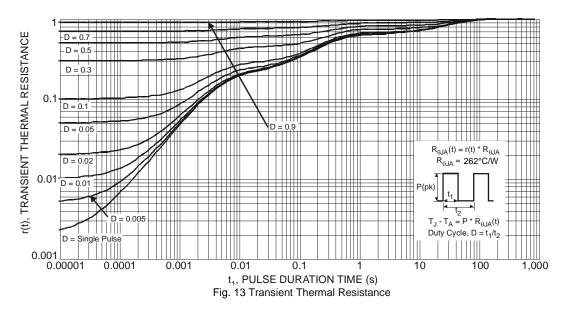








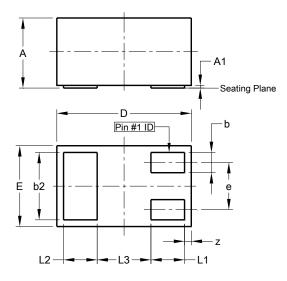






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



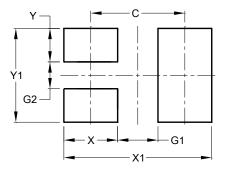
Х	X1-DFN1006-3					
Dim	Min	Max	Тур			
Α	0.47	0.53	0.50			
A1	0.00	0.05	0.03			
b	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95	1.075	1.00			
Е	0.55	0.675	0.60			
е	1	-	0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3	-	-	0.40			
z	0.02	0.08	0.05			
All D	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-3

X1-DFN1006-3



Dimensions	Value (in mm)			
С	0.70			
G1	0.30			
G2	0.20			
Х	0.40			
X1	1.10			
Y	0.25			
Y1	0.70			



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